SONY

ICX205AK

Diagonal 8mm (Type 1/2) Progressive Scan CCD Image Sensor with Square Pixel for Color Cameras

Description

The ICX205AK is a diagonal 8mm (Type 1/2) interline CCD solid-state image sensor with a square pixel array and 1.45M effective pixels. Progressive scan allows all pixels' signals to be output independently within approximately 1/7.5 second. Also, the adoption of high frame rate readout mode supports 30 frames per second. This chip features an electronic shutter with variable charge-storage time which makes it possible to realize full-frame still image without a mechanical shutter. High resolution and high color reproductivity are achieved through the use of R, G, B primary color mosaic filters. Further, high sensitivity and low dark current are achieved through the adoption of HAD (Hole-Accumulation Diode) sensors.

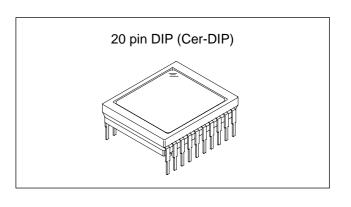
This chip is suitable for applications such as electronic still cameras, PC input cameras, etc.

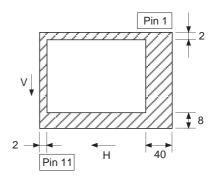
Features

- Progressive scan allows individual readout of the image signals from all pixels.
- High horizontal and vertical resolution (both approx. 800TV-lines) still image without a mechanical shutter.
- Supports high frame rate readout mode (effective 256 lines output, 30 frame/s)
- Square pixel
- Horizontal drive frequency: 14.318MHz
- No voltage adjustments

(reset gate and substrate bias are not adjusted.)

- R, G, B primary color mosaic filters on chip
- High resolution, high color reproductivity, high sensitivity, low dark current
- Low smear, excellent antiblooming characteristics
- Continuous variable-speed shutter





Optical black position (Top View)

Device Structure

• Interline CCD image sensor

• Image size: Diagonal 8mm (Type 1/2)

• Total number of pixels: 1434 (H) \times 1050 (V) approx. 1.50M pixels • Number of effective pixels: 1392 (H) \times 1040 (V) approx. 1.45M pixels

Number of active pixels: 1360 (H) × 1024 (V) approx. 1.40M pixels (7.959mm diagonal)

• Chip size: 7.60mm (H) × 6.20mm (V)
• Unit cell size: 4.65µm (H) × 4.65µm (V)

Optical black: Horizontal (H) direction: Front 2 pixels, rear 40 pixels
 Vertical (V) direction: Front 8 pixels, rear 2 pixels

Number of dummy bits: Horizontal 20

Vertical 3
• Substrate material: Silicon



* Wfine CCD is a registered trademark of Sony Corporation.
Represents a CCD adopting progressive scan, primary color filter and square pixel.

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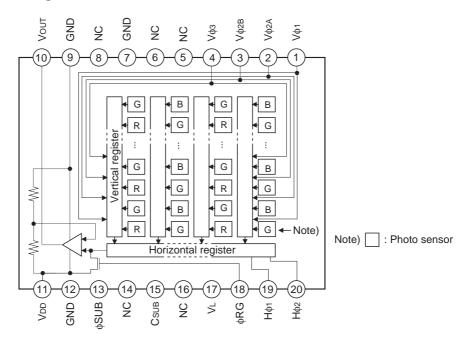
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Block Diagram and Pin Configuration

(Top View)



Pin Description

Pin No.	Symbol	Description	Pin No.	Symbol	Description
1	Vф1	Vertical register transfer clock	11	VDD	Supply voltage
2	Vф2A	Vertical register transfer clock	12	GND	GND
3	Vф2B	Vertical register transfer clock	13	φSUB	Substrate clock
4	Vфз	Vertical register transfer clock	14	NC	
5	NC		15	Сѕив	Substrate bias*1
6	NC		16	NC	
7	GND	GND	17	VL	Protective transistor bias
8	NC		18	φRG	Reset gate clock
9	GND	GND	19	Нф1	Horizontal register transfer clock
10	Vouт	Signal output	20	Нф2	Horizontal register transfer clock

^{*1} DC bias is generated within the CCD, so that this pin should be grounded externally through a capacitance of 0.1µF.

Absolute Maximum Ratings

	Item	Ratings	Unit	Remarks
	Vdd, Vout, фRG – фSUB	-40 to +10	V	
	Vφ2A, Vφ2B – φSUB	-50 to +15	V	
Against	Vφ1, Vφ3, VL – φSUB	-50 to +0.3	V	
	Hφ1, Hφ2, GND – φSUB	-40 to +0.3	V	
	Csub – \$SUB	–25 to	V	
	Vdd, Vout, фRG, Csuв – GND	-0.3 to +18	V	
Against GND	Vφ1, Vφ2A, Vφ2B, Vφ3 – GND	-10 to +18	V	
	Hφ1, Hφ2 – GND	-10 to +15	V	
Against \/	Vφ2A, Vφ2B – VL	-0.3 to +28	V	
Against V∟	Vφ1, Vφ3, Hφ1, Hφ2, GND – VL	-0.3 to +15	V	
	Voltage difference between vertical clock input pins	to +15	V	*1
Between input clock pins	Ηφ1 – Ηφ2	-16 to +16	V	
olook pillo	Ηφ1, Ηφ2 – Vφ3	-16 to +16	V	
Storage temper	ature	-30 to +80	°C	
Operating temp	erature	-10 to +60	°C	

^{*1 +24}V (Max.) when clock width < 10 μ s, clock duty factor < 0.1%.

⁺¹⁶V (Max.) is guaranteed for turning on or off power supply.

Bias Conditions

Item	Symbol	Min.	Тур.	Max.	Unit	Remarks
Supply voltage	VDD	14.55	15.0	15.45	V	
Protective transistor bias	VL		*1			
Substrate clock	φSUB		*2			
Reset gate clock	φRG		*2			

^{*1} VL setting is the V_{VL} voltage of the vertical transfer clock waveform, or the same power supply as the V_L power supply for the V driver should be used.

DC Characteristics

Item	Symbol	Min.	Тур.	Max.	Unit	Remarks
Supply current	IDD		5.5		mA	

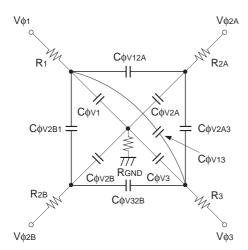
Clock Voltage Conditions

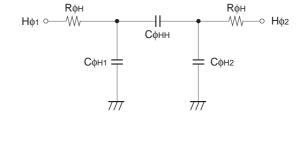
Item	Symbol	Min.	Тур.	Max.	Unit	Waveform diagram	Remarks
Readout clock voltage	Vvт	14.55	15.0	15.45	V	1	
	VvH02A	-0.05	0	0.05	V	2	Vvh = Vvh02A
	Vvh1, Vvh2A, Vvh2B, Vvh3	-0.2	0	0.05	V	2	
	VVL1, VVL2A, VVL2B, VVL3	-8.4	-8.0	-7.6	V	2	VVL = (VVL1 + VVL3)/2
Vertical transfer clock voltage	Vφ1, Vφ2A, Vφ2B, Vφ3	7.6	8.0	8.4	V	2	
	VVL1 — VVL3			0.1	V	2	
	V∨нн			0.9	V	2	High-level coupling
	VVHL			1.3	V	2	High-level coupling
	VVLH			1.0	V	2	Low-level coupling
	VVLL			0.9	V	2	Low-level coupling
Horizontal transfer	Vфн	4.75	5.0	5.25	V	3	
clock voltage	VHL	-0.05	0	0.05	V	3	
5	VφRG	3.0	3.3	5.5	V	4	
Reset gate clock voltage	Vrglh – Vrgll			0.4	V	4	Low-level coupling
	VRGL — VRGLm			0.5	V	4	Low-level coupling
Substrate clock voltage	Vфsuв	22.15	23.0	23.85	V	5	

^{*2} Do not apply a DC bias to the substrate clock and reset gate clock pins, because a DC bias is generated within the CCD.

Clock Equivalent Circuit Constant

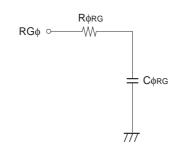
Item	Symbol	Min.	Тур.	Max.	Unit	Remarks
	Сф∨1		2200		pF	
Capacitance between vertical transfer clock ar	Сф∨2А		1800		pF	
GND	Сф∨2В		6800		рF	
	Сф∨з		3300		pF	
	СфV12А, СфV2В1		1200		pF	
Capacitance between vertical transfer clocks	Сфу2А3, Сфу32В		1200		pF	
	СфV13		2200		pF	
Capacitance between horizontal transfer clock and GND	Сфн1, Сфн2		47		pF	
Capacitance between horizontal transfer clocks	Сфнн		100		pF	
Capacitance between reset gate clock and GND	Сфяс		8		pF	
Capacitance between substrate clock and GND	Сфѕив		680		pF	
	R ₁		36		Ω	
Vertical transfer clock series resistor	R ₂ A, R ₃		56		Ω	
	R ₂ B		43		Ω	
Vertical transfer clock ground resistor	RGND		30		Ω	
Horizontal transfer clock series resistor	Rфн		15		Ω	
Reset gate clock series resistor	Rørg		20		Ω	





Vertical transfer clock equivalent circuit

Horizontal transfer clock equivalent circuit

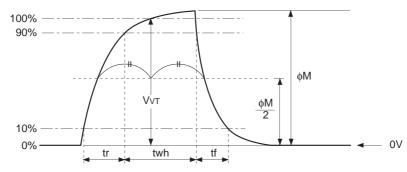


Reset gate clock equivalent circuit

Drive Clock Waveform Conditions

(1) Readout clock waveform

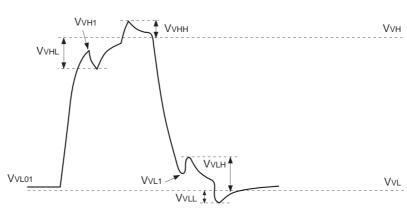




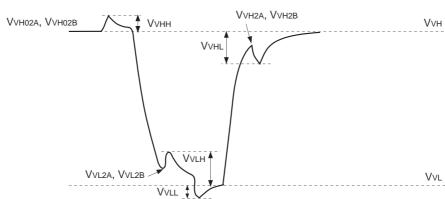
Note) Readout clock is used by composing vertical transfer clocks $V\phi_{2A}$ and $V\phi_{2B}$.

(2) Vertical transfer clock waveform

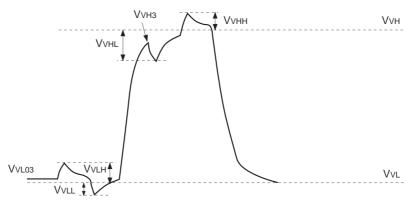




Vφ2A, Vφ2B



Vф3

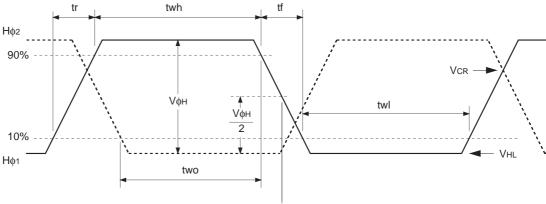


Vvh = Vvho2AVVI = (VVL01 + VVL03) / 2 VVL3 = VVL03

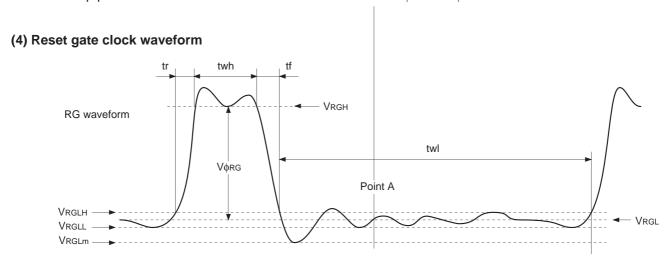
 $V\phi V1 = VVH1 - VVL01$ Vφν2A = VVH02A - VVL2A Vφν2B = VVH02B - VVL2B $V\phi V3 = VVH3 - VVL03$

−7 −

(3) Horizontal transfer clock waveform



Cross-point voltage for the H ϕ 1 rising side of the horizontal transfer clocks H ϕ 1 and H ϕ 2 waveforms is Vcr. The overlap period for twh and twl of horizontal transfer clocks H ϕ 1 and H ϕ 2 is two.



VRGLH is the maximum value and VRGLL is the minimum value of the coupling waveform during the period from Point A in the above diagram until the rising edge of RG.

In addition, VRGL is the average value of VRGLH and VRGLL.

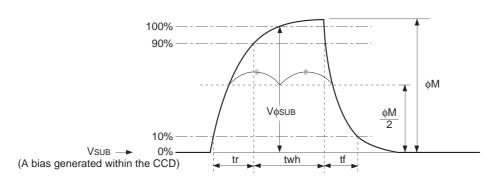
$$V_{RGL} = (V_{RGLH} + V_{RGLL})/2$$

Assuming VRGH is the minimum value during the interval twh, then:

$$V\phi RG = VRGH - VRGL$$
.

Negative overshoot level during the falling edge of RG is VRGLm.

(5) Substrate clock waveform



Clock Switching Characteristics

	Item	Symbol		twh			twl			tr			tf		Unit	Remarks
	Item	Symbol	Min.	Тур.	Мах.	Offic	Nemarks									
Rea	dout clock	VT	2.3	2.5						0.5			0.5		μs	During readout
Ver	tical transfer k	Vф1, Vф2A, Vф2B, Vф3										15		450	ns	*1
송	During	Нф1	20	25		20	25			10	15		10	15		*2
r clock	imaging	Нф2	20	25		20	25			10	15		10	15	ns	_
Horizontal transfer cl	During	Нф1								0.01			0.01			
를 Ta	parallel-serial conversion	Нф2								0.01			0.01		μs	
Res	et gate clock	фRG	11	13			51			3			3		ns	
Sub	strate clock	фѕив		2.2							0.5			0.5	μs	When draining charge

 $^{^{*1}\,}$ When vertical transfer clock driver CXD1267AN $\times\,2$ is used.

^{*2} tf \geq tr - 2ns, and the cross-point voltage (VcR) for the H ϕ 1 rising side of the H ϕ 1 and H ϕ 2 waveforms must be at least V ϕ H/2 [V].

Item	Symbol	two			Unit	Remarks	
item	Symbol	Min.	Тур.	Мах.	Offic	Remarks	
Horizontal transfer clock	Нф1, Нф2	16	20		ns		

Spectral Sensitivity Characteristics (excludes lens characteristics and light source characteristics)

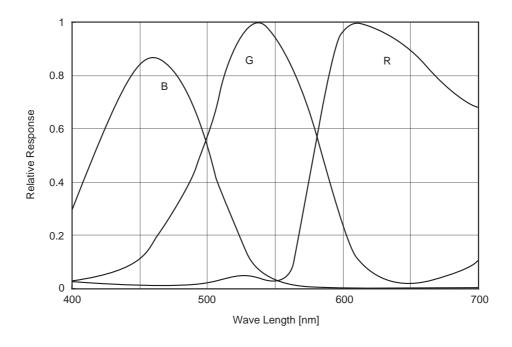
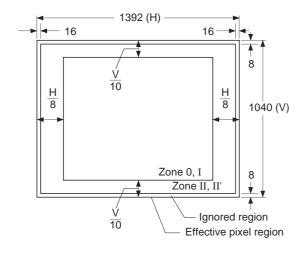


Image Sensor Characteristics

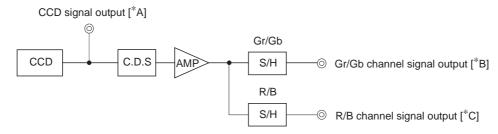
(Ta = 25°C)

Item		Symbol	Min.	Тур.	Max.	Unit	Measurement method	Remarks
G sensitivity		Sg	320	400		mV	1	1/30s accumulation
Sensitivity	R	Rr	0.4	0.55	0.7		1	
comparison	В	Rb	0.3	0.45	0.6		1	
Saturation signal		Vsat	450			mV	2	Ta = 60°C
Smear		Sm		0.001	0.0025	%	3	No electronic shutter
Mide e siened abadie e		SHg			20	%	4	Zone 0 and I
Video Signai Sha	Video signal shading				25	%	4	Zone 0 to II'
Uniformity between	en video	ΔSrg			8	%	5	
signal channels		∆Sbg			8	%	5	
Dark signal		Vdt			16	mV	6	Ta = 60°C
Dark signal shad	ding	ΔVdt			4	mV	7	Ta = 60°C
Line crawl G		Lcg			3.8	%	8	
Line crawl R		Lcr			3.8	%	8	
Line crawl B		Lcb			3.8	%	8	
Lag		Lag			0.5	%	9	

Zone Definition of Video Signal Shading



Measurement System



Note) Adjust the amplifier gain so that the gain between [*A] and [*B], and between [*A] and [*C] equals 1.

Image Sensor Characteristics Measurement Method

Color coding and readout of this image sensor

*	7	,	<u>'</u>
$\overline{\hspace{1em}}$	$\overline{\qquad}$	$\overline{\downarrow}$	\downarrow
R	Gr	R	Gr
Gb	В	Gb	В
R	Gr	R	Gr
Gb	В	Gb	В

The primary color filters of this image sensor are arranged in the layout shown in the figure on the left (Bayer arrangement).

Gr and Gb denote the G signals on the same line as the R signal and the B signal, respectively.

Horizontal register

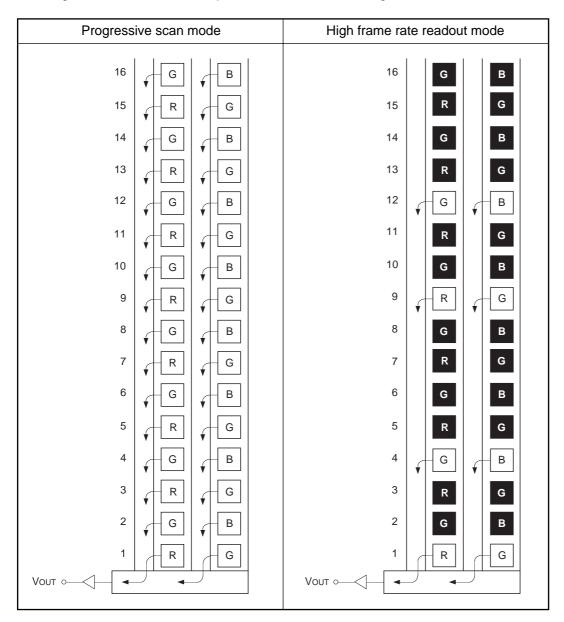
Color Coding Diagram

All pixel signals are output successively in a 1/7.5s period.

The R signal and Gr signal lines and the Gb signal and B signal lines are output successively.

Readout modes

The diagram below shows the output methods for the following two readout modes.



Note) Blacked out portions in the diagram indicate pixels which are not read out. Output starts from the line 1 in high frame rate readout mode.

1. Progressive scan mode

In this mode, all pixel signals are output in non-interlace format in 1/7.5s.

The vertical resolution is approximately 800TV-lines and all pixel signals within the same exposure period are read out simultaneously, making this mode suitable for high resolution image capturing.

2. High frame rate readout mode

All effective areas are scanned in approximately 1/30s by reading out two out of eight lines (1st and 4th lines, 9th and 12th lines). The vertical resolution is approximately 200TV-lines.

This readout mode emphasizes processing speed over vertical resolution.

Measurement conditions

1) In the following measurements, the device drive conditions are at the typical values of the progressive scan mode, bias and clock voltage conditions.

2) In the following measurements, spot blemishes are excluded and, unless otherwise specified, the optical black level (OB) is used as the reference for the signal output, which is taken as the value of the Gr/Gb signal output or the R/B signal output of the measurement system.

O Definition of standard imaging conditions

1) Standard imaging condition I:

Use a pattern box (luminance: 706cd/m², color temperature of 3200K halogen source) as a subject. (Pattern for evaluation is not applicable.) Use a testing standard lens with CM500S (t = 1.0mm) as an IR cut filter and image at F5.6. The luminous intensity to the sensor receiving surface at this point is defined as the standard sensitivity testing luminous intensity.

2) Standard imaging condition II:

Image a light source (color temperature of 3200K) with a uniformity of brightness within 2% at all angles. Use a testing standard lens with CM500S (t = 1.0mm) as an IR cut filter. The luminous intensity is adjusted to the value indicated in each testing item by the lens diaphragm.

1. G sensitivity, sensitivity comparison

Set to standard imaging condition I. After selecting the electronic shutter mode with a shutter speed of 1/100s, measure the signal outputs (V_{Gr}, V_{Gb}, V_R and V_B) at the center of each Gr, Gb, R and B channel screen, and substitute the values into the following formulas.

$$V_G = (V_{Gr} + V_{Gb})/2$$

 $Sg = V_G \times 100/30 \text{ [mV]}$
 $Rr = V_R/V_G$

Rb = VB/VG

2. Saturation signal

Set to standard imaging condition II. After adjusting the luminous intensity to 20 times the intensity with the average value of the Gr signal output, 150mV, measure the minimum values of the Gr, Gb, R and B signal outputs.

3. Smear

Set to standard imaging condition II. With the lens diaphragm at F5.6 to F8, first adjust the average value of the Gr signal output to 150mV. Measure the average values of the Gr signal output, Gb signal output, R signal output and B signal output (Gra, Gba, Ra, Ba), and then adjust the luminous intensity to 500 times the intensity with the average value of the Gr signal output, 150mV. After the readout clock is stopped and the charge drain is executed by the electronic shutter at the respective H blankings, measure the maximum value (Vsm [mV]) independent of the Gr, Gb, R and B signal outputs, and substitute the values into the following formula.

$$Sm = Vsm \div \frac{Gra + Gba + Ra + Ba}{4} \times \frac{1}{500} \times \frac{1}{10} \times 100 \text{ [\%] (1/10V method conversion value)}$$

4. Video signal shading

Set to standard imaging condition II. With the lens diaphragm at F5.6 to F8, adjust the luminous intensity so that the average value of the Gr signal output is 150mV. Then measure the maximum (Grmax [mV]) and minimum (Grmin [mV]) values of the Gr signal output and substitute the values into the following formula.

SHg =
$$(Grmax - Grmin)/150 \times 100$$
 [%]

5. Uniformity between video signal channels

After measuring 4, measure the maximum (Rmax [mV]) and minimum (Rmin [mV]) values of the R signal and the maximum (Bmax [mV]) and minimum (Bmin [mV]) values of the B signal, and substitute the values into the following formulas.

$$\Delta$$
Srg = (Rmax - Rmin)/150 × 100 [%]
 Δ Sbg = (Bmax - Bmin)/150 × 100 [%]

6. Dark signal

Measure the average value of the signal output (Vdt [mV]) with the device ambient temperature 60°C and the device in the light-obstructed state, using the horizontal idle transfer level as a reference.

7. Dark signal shading

After measuring 6, measure the maximum (Vdmax [mV]) and minimum (Vdmin [mV]) values of the dark signal output and substitute the values into the following formula.

$$\Delta Vdt = Vdmax - Vdmin [mV]$$

8. Line crawl

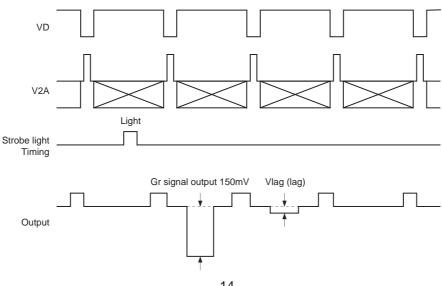
Set to standard imaging condition II. Adjusting the luminous intensity so that the average value of the Gr signal output is 150mV, and then insert R, G and B filters and measure the difference between G signal lines (Δ Glr, Δ Glg, Δ Glb [mV]) as well as the average value of the G signal output (Gar, Gag, Gab). Substitute the values into the following formula.

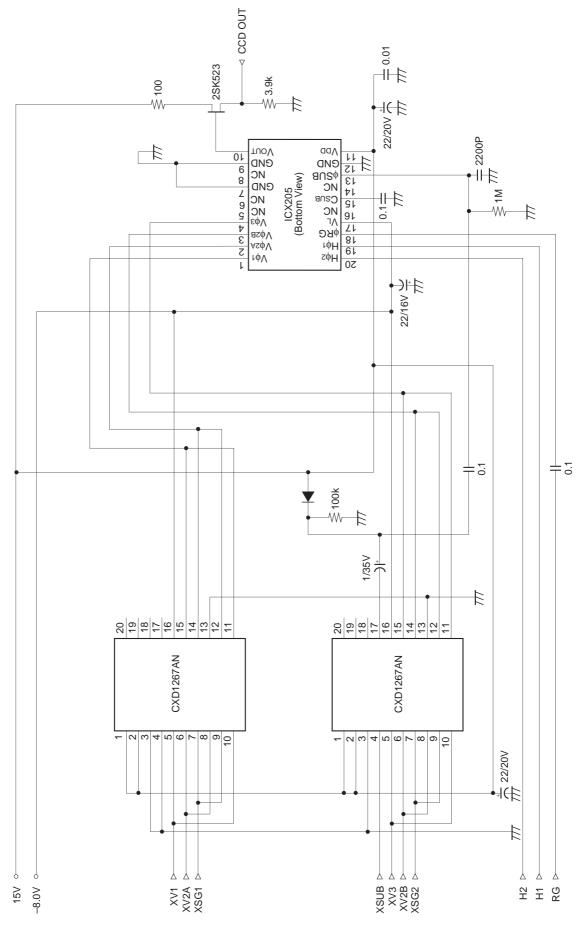
Lci =
$$\Delta$$
Gli/Gai × 100 [%] (i = r, g, b)

9. Lag

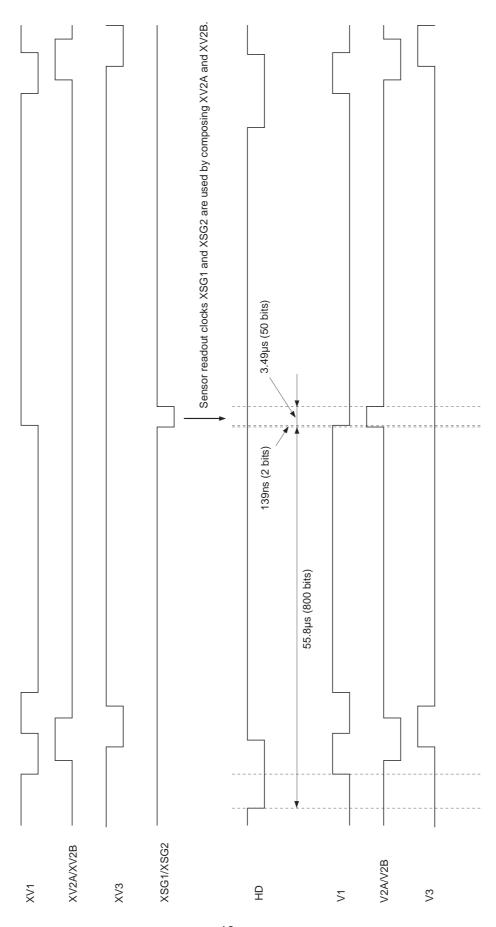
Adjust the Gr signal output value generated by strobe light to 150mV. After setting the strobe light so that it strobes with the following timing, measure the residual signal (Vlag). Substitute the value into the following formula.

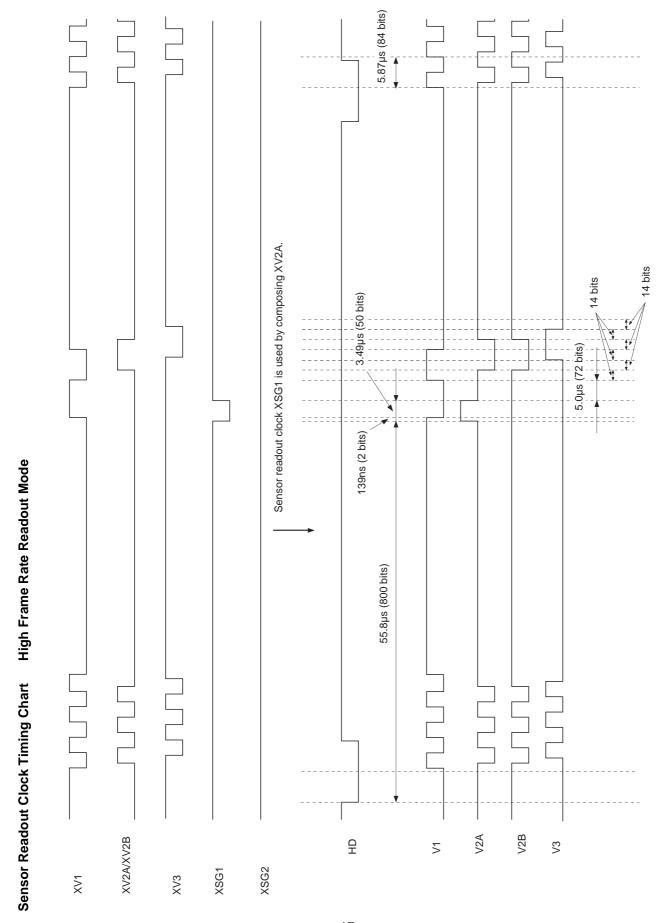
$$Lag = (Vlag/150) \times 100 [\%]$$



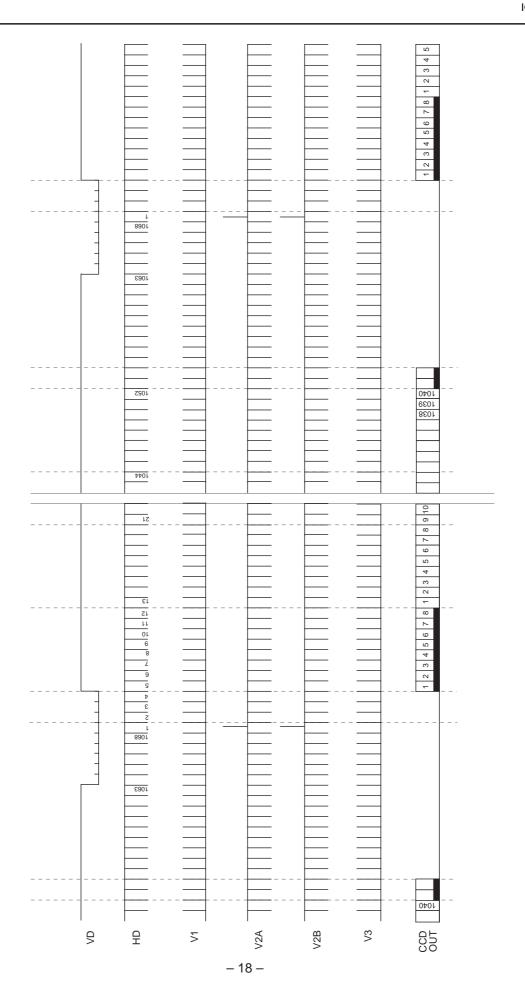


Sensor Readout Clock Timing Chart Progressive Scan Mode

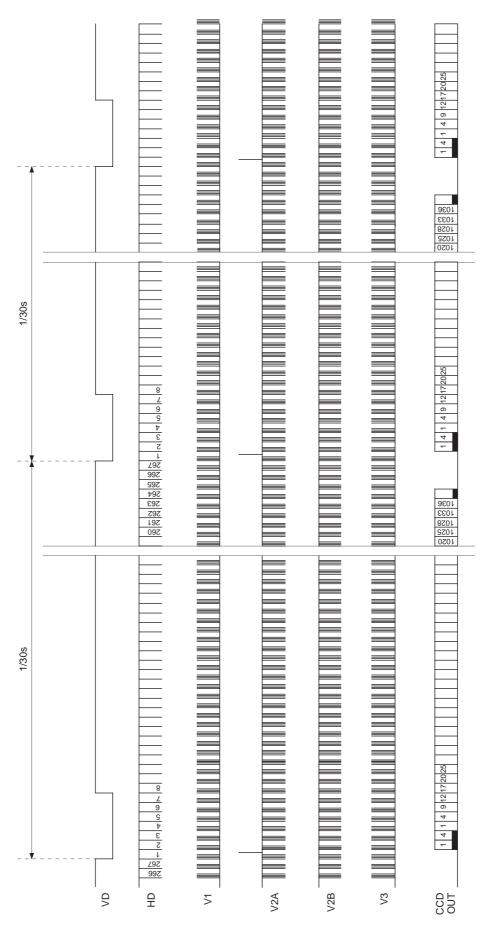


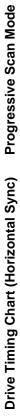


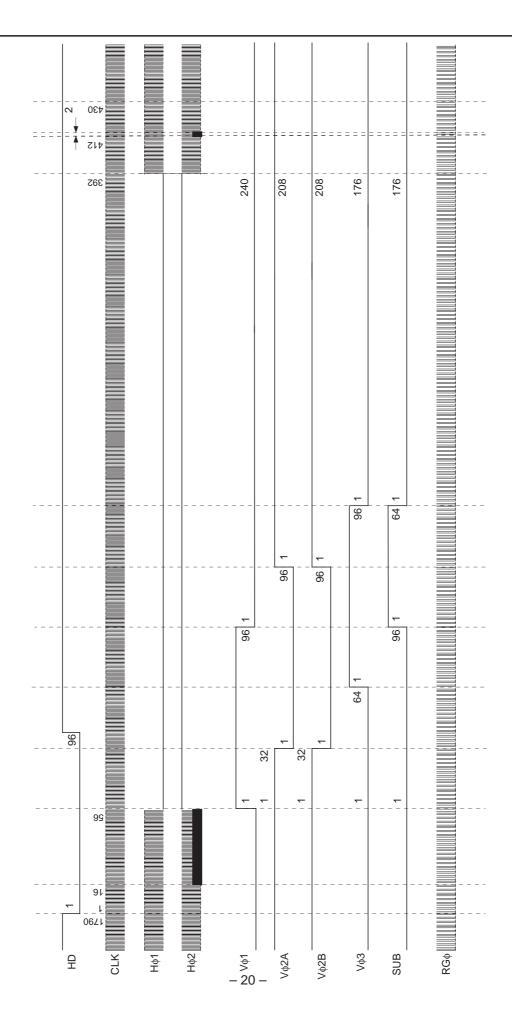




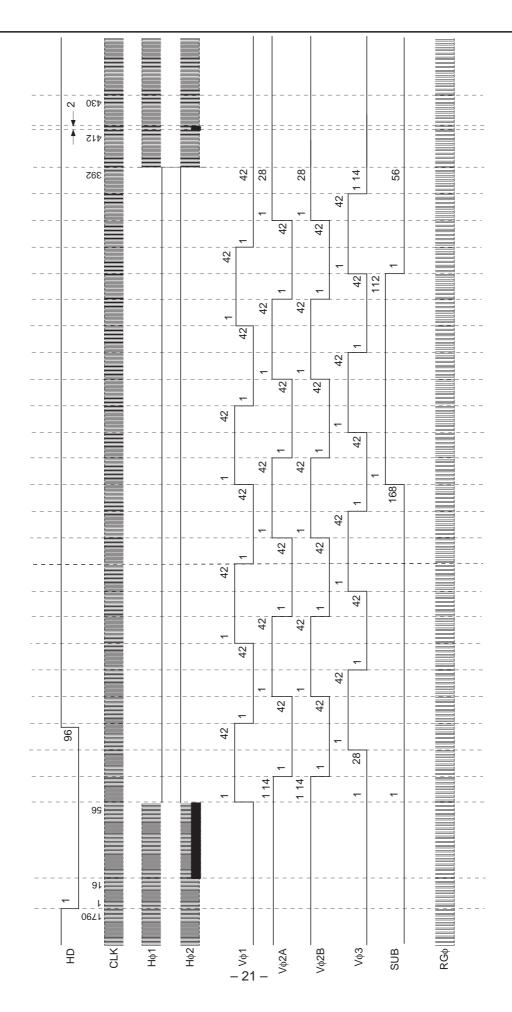
Drive Timing Chart (Vertical Sync) High Frame Rate Readout Mode







Drive Timing Chart (Horizontal Sync) High Frame Rate Readout Mode



Notes on Handling

1) Static charge prevention

CCD image sensors are easily damaged by static discharge. Before handling be sure to take the following protective measures.

- a) Either handle bare handed or use non-chargeable gloves, clothes or material. Also use conductive shoes.
- b) When handling directly use an earth band.
- c) Install a conductive mat on the floor or working table to prevent the generation of static electricity.
- d) Ionized air is recommended for discharge when handling CCD image sensor.
- e) For the shipment of mounted substrates, use boxes treated for the prevention of static charges.

2) Soldering

- a) Make sure the package temperature does not exceed 80°C.
- b) Solder dipping in a mounting furnace causes damage to the glass and other defects. Use a ground 30W soldering iron and solder each pin in less than 2 seconds. For repairs and remount, cool sufficiently.
- c) To dismount an image sensor, do not use a solder suction equipment. When using an electric desoldering tool, use a thermal controller of the zero cross On/Off type and connect it to ground.

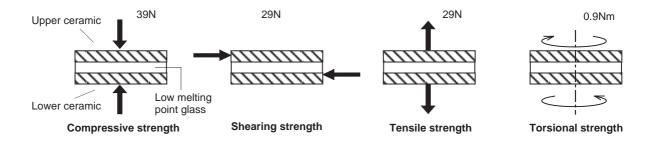
3) Dust and dirt protection

Image sensors are packed and delivered by taking care of protecting its glass plates from harmful dust and dirt. Clean glass plates with the following operation as required, and use them.

- a) Perform all assembly operations in a clean room (class 1000 or less).
- b) Do not either touch glass plates by hand or have any object come in contact with glass surfaces. Should dirt stick to a glass surface, blow it off with an air blower. (For dirt stuck through static electricity ionized air is recommended.)
- c) Clean with a cotton bud and ethyl alcohol if the grease stained. Be careful not to scratch the glass.
- d) Keep in a case to protect from dust and dirt. To prevent dew condensation, preheat or precool when moving to a room with great temperature differences.
- e) When a protective tape is applied before shipping, just before use remove the tape applied for electrostatic protection. Do not reuse the tape.

4) Installing (attaching)

a) Remain within the following limits when applying a static load to the package. Do not apply any load more than 0.7mm inside the outer perimeter of the glass portion, and do not apply any load or impact to limited portions. (This may cause cracks in the package.)



- b) If a load is applied to the entire surface by a hard component, bending stress may be generated and the package may fracture, etc., depending on the flatness of the ceramic portions. Therefore, for installation, use either an elastic load, such as a spring plate, or an adhesive.
- c) The adhesive may cause the marking on the rear surface to disappear, especially in case the regulated voltage value is indicated on the rear surface. Therefore, the adhesive should not be applied to this area, and indicated values should be transferred to other locations as a precaution.
- d) The upper and lower ceramic are joined by low melting point glass. Therefore, care should be taken not to perform the following actions as this may cause cracks.
 - Applying repeated bending stress to the outer leads.
 - Heating the outer leads for an extended period with a soldering iron.
 - Rapidly cooling or heating the package.
 - Applying any load or impact to a limited portion of the low melting point glass using tweezers or other sharp tools.
 - Prying at the upper or lower ceramic using the low melting point glass as a fulcrum.

Note that the same cautions also apply when removing soldered products from boards.

e) Acrylate anaerobic adhesives are generally used to attach CCD image sensors. In addition, cyanoacrylate instantaneous adhesives are sometimes used jointly with acrylate anaerobic adhesives. (reference)

5) Others

- a) Do not expose to strong light (sun rays) for long periods, color filters will be discolored. When high luminance objects are imaged with the exposure level control by electronic-iris, the luminance of the image-plane may become excessive and discolor of the color filter will possibly be accelerated. In such a case, it is advisable that taking-lens with the automatic-iris and closing of the shutter during the power-off mode should be properly arranged. For continuous using under cruel condition exceeding the normal using condition, consult our company.
- b) Exposure to high temperature or humidity will affect the characteristics. Accordingly avoid storage or usage in such conditions.

Unit: mm Package Outline

The height from the bottom "C" to the effective image area is 1.41 \pm 0.15mm. The rotation angle of the effective image area relative to H and V is $\pm\,$ 1 $^{\circ}$. The center of the effective image area, relative to "B" and "B" is (H, V) = (9.0, 7.55) $\pm\,0.15$ mm. The two points "B" of the package are the horizontal reference. The bottom "C" of the package is the height reference. The point "B" of the package is the vertical reference. (1.7) (0.4) 24 "A" is the center of the effective image area. 41.4 (R_{0.7}) (1.0) 4.1 °6 of °0 62.0 ပ 20 pin DIP (600mil) რ 4. 5 9 €.0 ± 0.4 £.0 ± ₽.£ 15.24 0.46 N <u>~</u> 0.8 7.0 15.1 ± 0.3 10 က 4 1.778 18.0 ± 0.4 (\mathbf{z}) 14.6 0.3 9.0 0.4 \oplus 20 25.T ₽.0 13.0 33.11 3 0.7 99.0 3

PACKAGE STRUCTURE

PACKAGE MATERIAL	Cer-DIP
LEAD TREATMENT	TIN PLATING
LEAD MATERIAL	42 ALLOY
PACKAGE MASS	2.60g
DRAWING NUMBER	AS-B2-02(E)

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The thickness of the cover glass is 0.75mm, and the refractive index is 1.5.

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The tilt of the effective image area relative to the bottom "C" is less than 60μm.